Vishay Semiconductors

# High Performance Schottky Rectifier, 1.5 A



SMA (DO-214AC)

PRODUCT SUMMARY			
Package	SMA (DO-214AC)		
I <sub>F(AV)</sub>	1.5 A		
V <sub>R</sub>	40 V		
V <sub>F</sub> at I <sub>F</sub>	0.43 V		
I <sub>RM</sub>	20 mA at 125 °C		
T <sub>J</sub> max.	150 °C		
Diode variation	Single		
E <sub>AS</sub>	6.0 mJ		

#### **FEATURES**

- Surface mountable
- Extremely low forward voltage
- Compact size
- Improved reverse blocking voltage capability relative to other similar size Schottky
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### APPLICATIONS

- Switching power supplies
- Meter protection
- · Reverse protection for power input to PC board circuits
- Battery isolation and charging
- · Low threshold voltage diode
- · Freewheeling or by-pass diode
- Low voltage clamp

### DESCRIPTION

The VS-15MQ040NTRPbF Schottky rectifier is designed to be used for low power applications where a reverse voltage of 40 V is encountered and surface mountable is required.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	1.5	A		
V <sub>RRM</sub>		40	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	330	А		
V <sub>F</sub>	2 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.43	V		
TJ	Range	-40 to +150	°C		

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-15MQ040NTRPbF	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	40	
Maximum working peak reverse voltage	V <sub>RWM</sub>	40	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDIT	TEST CONDITIONS VALUES U		
Maximum average forward current See fig. 4		50 % duty cycle at T <sub>L</sub> = 105 °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)		2.1	A
		50 % duty cycle at $T_L$ = 114 °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)		1.5	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	330	
non-repetitive surge current See fig. 6	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	140	A
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 12 \text{ mH}$ 6.0		mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 1.0		А	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CC	ONDITIONS	VALUES	UNITS
		1 A	T <sub>1</sub> = 25 °C	0.42	V
Maximum forward voltage drop	V (1)	2 A	1J=25 C	0.49	
See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	1 A	T 105 %C	0.34	
		2 A	− T <sub>J</sub> = 125 °C	0.43	
Maximum reverse leakage current See fig. 2	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	0.5	mA
		T <sub>J</sub> = 125 °C		20	
Threshold voltage	V <sub>F(TO)</sub>	$T_{\rm J} = T_{\rm J} \text{ maximum} \qquad \qquad$		0.26	V
Forward slope resistance	r <sub>t</sub>			mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}$ , $T_J = 25 \text{ °C}$ , test signal = 1 MHz 134		pF	
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body 2.0		nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V		V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-40 to +150	°C
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	80	°C/W
Approvimento weight			0.07	g
Approximate weight			0.002	oz.
Marking device		Case style SMA (DO-214AC) (similar D-64)	Х	F

#### Note

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$ (1)



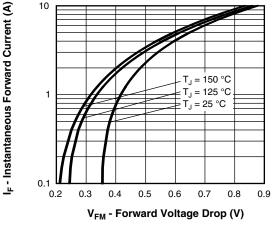


Fig. 1 - Maximum Forward Voltage Drop Characteristics

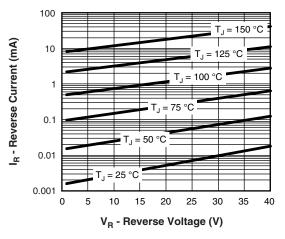


Fig. 2 - Typical Peak Reverse Current vs.Reverse Voltage

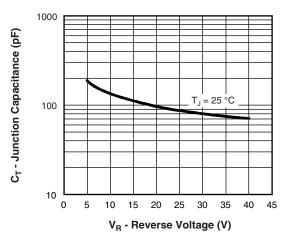


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

## VS-15MQ040NTRPbF

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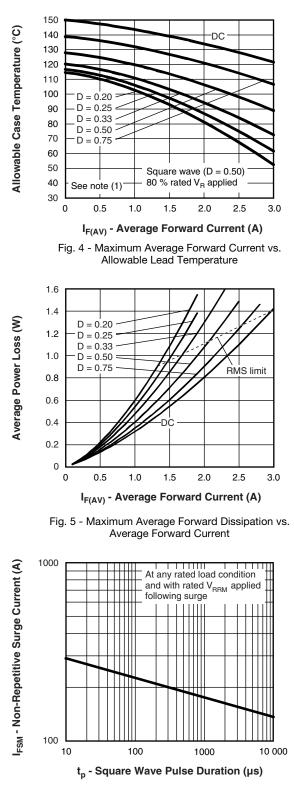


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times V_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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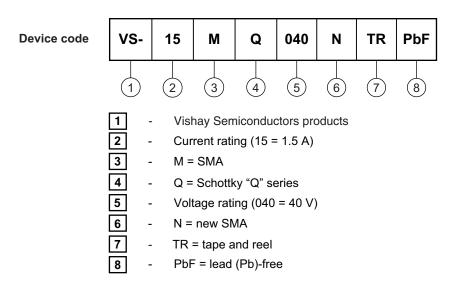
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### **Vishay Semiconductors**

### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-15MQ040NTRPbF	5AT	7500	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95400				
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			
SPICE model	www.vishay.com/doc?95273			



# **Outline Dimensions**

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SMA

### **DIMENSIONS** in inches (millimeters)

DO-214AC (SMA)





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